

MMBD914

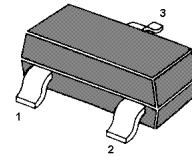
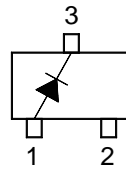
High Speed Switching Diode

Features

- Small package
- Low forward voltage
- Fast reverse recovery time
- Small total capacitance

Applications

- Ultra high speed switching application



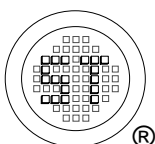
Marking Code: **5D**
SOT-23 Plastic Package

Absolute Maximum Ratings ($T_a = 25\text{ }^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Reverse Voltage	V_R	100	V
Forward Current	I_F	200	mA
Peak Forward Surge Current	I_{FSM}	500	mA
Power Dissipation	P_{tot}	300	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_s	- 55 to + 150	$^\circ\text{C}$

Characteristics at $T_a = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Min.	Max.	Unit
Forward Voltage at $I_F = 10\text{ mA}$	V_F	-	1	V
Reverse Breakdown Voltage at $I_R = 100\text{ }\mu\text{A}$	$V_{(BR)R}$	100	-	V
Reverse Current at $V_R = 20\text{ V}$ at $V_R = 75\text{ V}$	I_R	-	25 5	nA μA
Reverse Recovery Time at $I_F = I_R = 10\text{ mA}$	t_{rr}	-	4	ns
Total Capacitance at $V_R = 0$, $f = 1\text{ MHz}$	C_T	-	4	pF



SEMTECH ELECTRONICS LTD.

(Subsidiary of Sino-Tech International Holdings Limited, a company
listed on the Hong Kong Stock Exchange, Stock Code: 724)



ISO/TS 16949 : 2002
Certificate No. 05103



ISO 14001:2004
Certificate No. 7116



ISO 9001:2000
Certificate No. 0506088

Dated : 22/01/2008

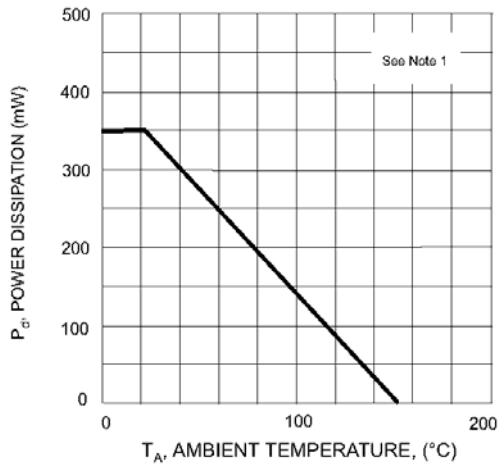


Fig. 1 Power Derating Curve

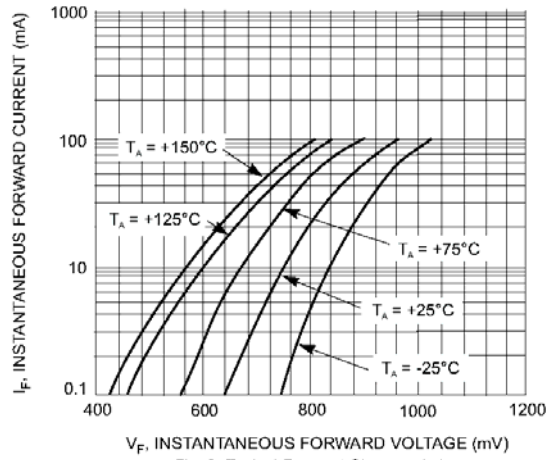


Fig. 2, Typical Forward Characteristics

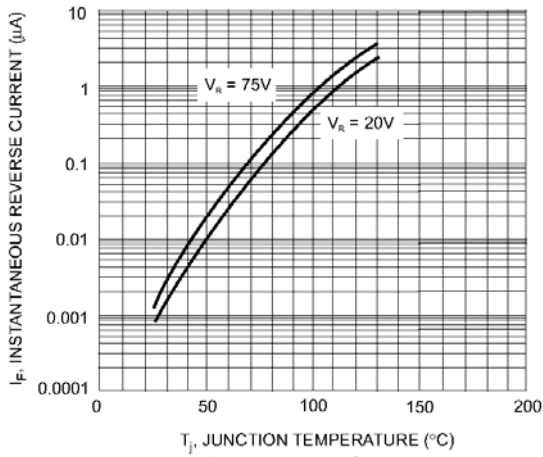
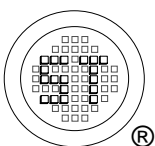


Fig. 3, Typical Reverse Characteristics



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